## NSN 5961-01-463-3658

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-463-3658 **Inclosure Material:** Glass **Overall Length:** 2.160 millimeters **Terminal Length:** 0.160 millimeters **End Application:** Rsippple/ifscm97942 **Mounting Method:** Compression **Terminal Circle Diameter:** 0.004 millimeters **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 reverse breakdown voltage, dc and 0.4 forward voltage, dc **Current Rating Per Characteristic:** 500.00 nanoamperes forward current, average peak **Power Rating Per Characteristic:** 125.0 milliwatts small-signal input power, common-emitter peak **Maximum Operating Tempurature Per Measurement Point:** -55.0 degrees celsius case and 100.0 degrees celsius case **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No

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